# μESD3.3DT5G SERIES

# **ESD Protection Diodes**

# Ultra Small SOT-723 Package

The  $\mu ESD$  Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications.

## **Specification Features:**

• Small Body Outline Dimensions:

0.047" x 0.032" (1.20 mm x 0.80 mm)

• Low Body Height: 0.020" (0.5 mm)

• Stand-off Voltage: 3.3 V - 6.0 V

• Low Leakage

• Response Time is Typically < 1 ns

• ESD Rating of Class 3 (> 16 kV) per Human Body Model

• IEC61000-4-2 Level 4 ESD Protection

• IEC61000-4-4 Level 4 EFT Protection

• AEC-Q101 Qualified and PPAP Capable

• These are Pb-Free Devices

## **Mechanical Characteristics:**

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

**LEAD FINISH:** 100% Matte Sn (Tin)

**MOUNTING POSITION:** Any

**QUALIFIED MAX REFLOW TEMPERATURE: 260°C** 

Device Meets MSL 1 Requirements

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air Contact		±30 ±30	kV
IEC 61000-4-4 (EFT)		40	Α
ESD Voltage Per Human Body Model Per Machine Model		16 400	kV V
Total Power Dissipation on FR-5 Board (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C Thermal Resistance Junction-to-Ambient	$P_{D}$	240 1.9 525	mW mW/°C °C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	$T_L$	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $FR-5 = 1.0 \times 0.75 \times 0.62$  in.

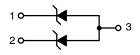


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#### www.onsemi.com

PIN 1. CATHODE 2. CATHODE

3. ANODE





SOT-723 CASE 631AA STYLE 4





xx = Device Code M = Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
UESDxxDT5G	SOT-723	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **DEVICE MARKING INFORMATION**

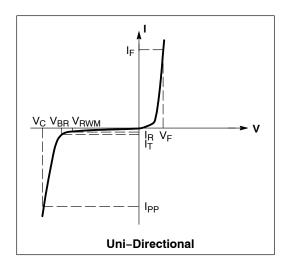
See specific marking information in the device marking column of the table on page 2 of this data sheet.

# μESD3.3DT5G SERIES

## **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

١ ٨	•
Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
$V_{RWM}$	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>
Ι <sub>Τ</sub>	Test Current
I <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>
P <sub>pk</sub>	Peak Power Dissipation
С	Max. Capacitance @V <sub>R</sub> = 0 and f = 1 MHz



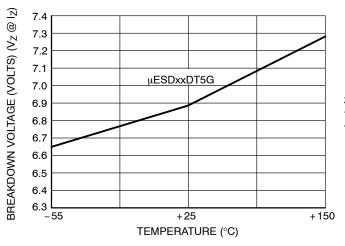
# $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{A} = 25^{\circ}\text{C unless otherwise noted}, \ V_{F} = 1.1 \ V \ \text{Max.} \ @ \ I_{F} = 10 \ \text{mA for all types})$

	Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (μΑ) @ V <sub>RWM</sub>	V <sub>BR</sub> (V) @ I <sub>T</sub> (Note 2)	I <sub>T</sub>	C (pF)
Device*	Marking	Max	Max	Min	mA	Тур
UESD3.3DT5G	L0	3.3	1.0	5.0	1.0	47
UESD5.0DT5G	L2	5.0	0.1	6.2	1.0	38
UESD6.0DT5G	L3	6.0	0.1	7.0	1.0	34

<sup>\*</sup>Other voltages available upon request. 2.  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C.

## μESD3.3DT5G SERIES

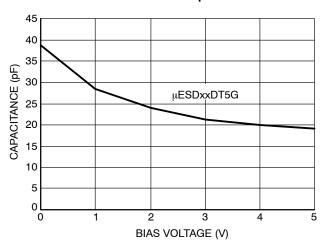
## **TYPICAL CHARACTERISTICS**



20 18 16 14 12 I<sub>R</sub> (nA) 10 8 6 μESDxxDT5G 4 2 0 -55 +25 +150 TEMPERATURE (°C)

Figure 1. Typical Breakdown Voltage versus Temperature

Figure 2. Typical Leakage Current versus Temperature



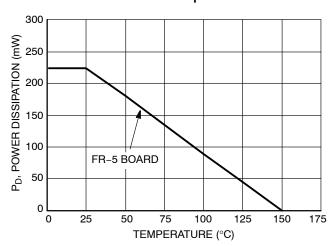
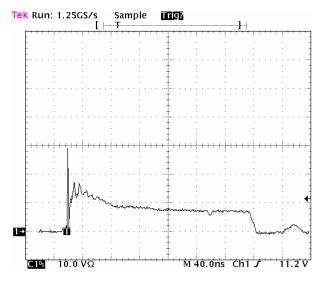


Figure 3. Typical Capacitance versus Bias Voltage

Figure 4. Steady State Power Derating Curve



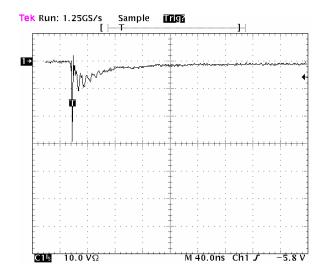


Figure 5. Positive 8 kV contact per IEC 6100-4-2  $- \mu ESD5.0DT5G$ 

Figure 6. Negative 8 kV contact per IEC 61000-4-2  $- \mu ESD5.0DT5G$ 



SOT-723 CASE 631AA-01 ISSUE D

**DATE 10 AUG 2009** 

#### NOTES:

- NOTES.

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD
- FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.45	0.50	0.55
b	0.15	0.21	0.27
b1	0.25	0.31	0.37
С	0.07	0.12	0.17
D	1.15	1.20	1.25
E	0.75	0.80	0.85
е	0.40 BSC		
ΗE	1.15	1.20	1.25
L	0.29 REF		
L2	0.15	0.20	0.25

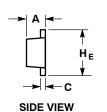
## **GENERIC** MARKING DIAGRAM\*

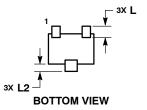


= Specific Device Code XX Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

# -X-2X b ⊕ 0.08 X Y **TOP VIEW**

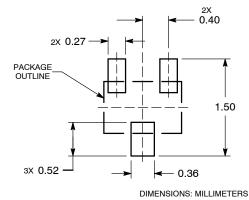




STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

STYLE 4: PIN 1. CATHODE STYLE 5: PIN 1. GATE 2. CATHODE 3. ANODE 2. SOURCE 3. DRAIN

**RECOMMENDED SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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